JAN 1 3 JUD3

ÈATENT 2992\$137672

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of: Young-Hun Bae and I hereby certify that this paper and the documents referred to as enclosed Won-Sung Park therewith are being deposited with the United States Postal Service as first Serial No.: 09/940,774 class mail, postage prepaid, on January 9, 2003, in an envelope Filed: August 27, 2001 addressed to Commissioner for Patents, Washington, D.C. 20231. For: Method for Forming a Gate of a High Integration Semiconductor Device Group Art Unit: 2811 Reg. No. 35,902 Examiner: Donghee Kang Attorney for Applicants

RESPONSE TO RESTRICTION REQUIREMENT

Commissioner for Patents Washington, D.C. 20231

Sir:

In response to the restriction requirement imposed in the office action mailed on December 9, 2002, applicants hereby elect Group II, claims 3-5 and 8-10, with traverse.

An early office action on the merits of this application is respectfully solicited.

The Commissioner is authorized to charge any fee deficiency required by this paper, or credit any overpayment, to Deposit Account No. 13-2855.

Respectfully submitted,

MARSHALL, GERSTEIN & BORUN 6300 Sears Tower

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January 9, 2003

By:

Michael R. Hull Reg. No. 35,902